

MITSUBISHI (OPTICAL DEVICES)

FU-423SLD-F3M31

1.3 μm LD MODULE WITH SINGLEMODE FIBER PIGTAIL

DESCRIPTION

Module type FU-423SLD-F3M31 has been developed for coupling a singlemode optical fiber and a 1.3 μm wavelength InGaAsP LD (Laser diode).

FU-423SLD-F3M31 is suitable to light source for high-speed short haul and long haul digital optical communication systems.

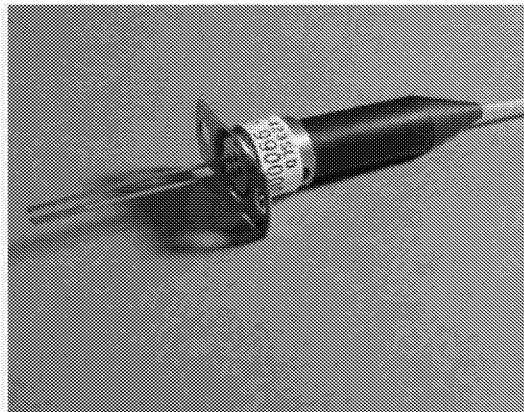
FEATURES

- High-speed response
- Emission wavelength is in 1.3 μm band
- Low threshold current (7mA typ.)
- With photodiode for optical output monitor

- MQW* active layer
- FSBH** structure fabricated by all MOCVD process

*Multiple quantum well

**Facet selective-growth buried heterostructure



APPLICATION

Trunk Line, FiT

ABSOLUTE MAXIMUM RATINGS (Tc=25°C)

Parameter	Symbol	Conditions	Rating	Unit
Laser diode	Pf	CW Tc=-40~85°C	0.4	mW
	Vrl	-	2	V
Photodiode for monitoring	Vrd	-	20	V
	Ifd	-	2	mA
Operating case temperature	Tc	-	-40~+85	°C
Storage temperature	Tstg	-	-40~+85	°C

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ELECTRICAL/OPTICAL CHARACTERISTICS

Parameter	Symbol	Test Conditions	Limits			Unit
			Min.	Typ.	Max.	
Threshold current	I _{th}	CW,T _c =25°C	3	6	10	mA
		CW,T _c =-40~85°C	1	-	35	
Modulation current	I _{mod}	CW,P _f =0.2mW, T _c =25°C	5	6	15	mA
		CW,APC, I _{mon} (P _f (25°C)=0.2mW), T _c =-40~85°C	4	-	35	
Operating Voltage	V _{op}	CW,APC, I _{mon} (P _f (25°C)=0.2mW), T _c =-40~85°C	0.8	-	1.5	V
Threshold power	P _{fth}	CW,I _f =I _{th} ,T _c =-40~85°C (Note1)	-	-	10	μW
dP _f /dI _f linearity	η _I	CW,APC,P _f =0.04~0.2mW	-25	-	25	%
Center wavelength	λ _c	CW,P _f =0.2mW, T _c =25°C	1290	-	1330	nm
		CW,APC, I _{mon} (P _f (25°C)=0.2mW), T _c =-40~85°C	1260	-	1360	
Spectral width(RMS) (Note 3)	Δλ	CW,APC, I _{mon} (P _f (25°C)=0.2mW), T _c =-40~85°C	-	-	2.5	nm
Rise and fall times	t _{r,tf}	I _b =I _{th} ,P _{fpeak} =0.2mW, 10~90%,T _c =25°C	-	0.3	0.5	ns
Tracking error (Note2)	Er	CW,APC, I _{mon} (P _f (25°C)=0.2mW), T _c =0~70°C	0	0.4	1	dB
		CW,APC, I _{mon} (P _f (25°C)=0.2mW), T _c =-40~85°C	0	0.5	1.2	
Monitor current	I _{mon}	CW,V _{rd} =3V,P _f =0.2mW	0.08	0.5	1	mA
Dark current (Photodiode)	I _d	V _{rd} =3V	-	0.1	0.5	μA
Capacitance (Photodiode)	C _t	V _{rd} =3V,f=1MHz	-	-	15	pF

Note 1. If is ward current of LD.

2. Er=MAX|10×log(P_f(T_c)/P_f(25°C))|

3. Δλ=((Σai*(λ_i-λ_c)²)/Σai)^{1/2}

Where ai≥ap×0.01

ai:Relative intensty of laser spectral emission modes

ap:Peak of laser spectral emission modes

OPTICAL FIBER SPECIFICATION

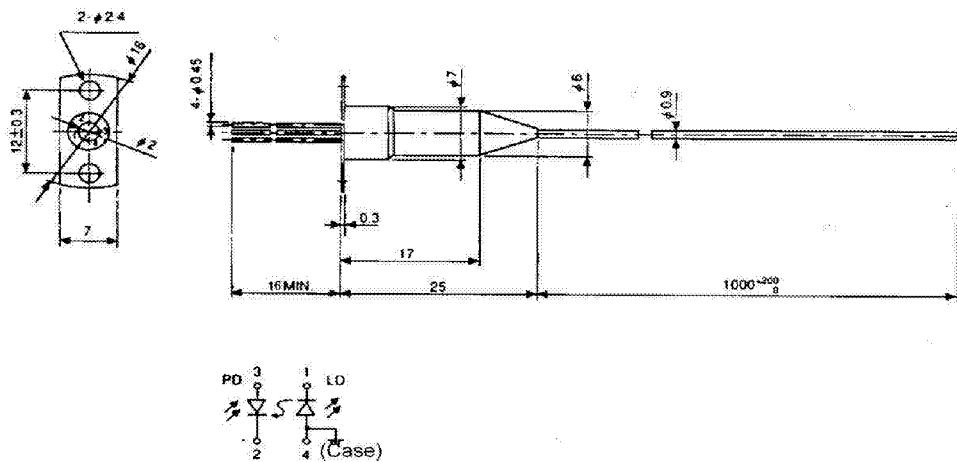
Parameter	Limits	Unit
Type	SM	-
Mode field dia.	9.5±1	μm
Cladding dia.	125±2	μm
Jacket dia.	0.9 typ.	mm

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OUTLINE DIAGRAM

(Unit : mm)



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